Medium-Power Plastic NPN Silicon Transistors

These high-performance plastic devices are designed for driver circuits, switching, and amplifier applications.

Features

- Low Saturation Voltage
- Excellent Power Dissipation Due to Thermopad[™] Construction
- Excellent Safe Operating Area
- Complement to PNP 2N4920G
- These Devices are Pb-Free and are RoHS Compliant**

MAXIMUM RATINGS				
Rating	Symbol	Value	Unit	
Collector–Emitter Voltage 2N4921G 2N4922G 2N4923G	V _{CEO}	40 60 80	Vdc	
Collector–Emitter Voltage 2N4921G 2N4922G 2N4923G	V _{CB}	40 60 80	Vdc	
Emitter Base Voltage	V_{EB}	5.0	Vdc	
Collector Current – Continuous (Note 1)	Ι _C	1.0	Adc	
Collector Current – Peak (Note 1)	I _{CM}	3.0	Adc	
Base Current – Continuous	Ι _Β	1.0	Adc	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D	30 0.24	W mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The 1.0 A maximum I_C value is based upon JÉDEC current gain requirements. The 3.0 A maximum value is based upon actual current handling capability of the device (see Figures 5 and 6).

THERMAL CHARACTERISTICS (Note 2)

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ ext{ heta}JC}$	4.16	°C/W

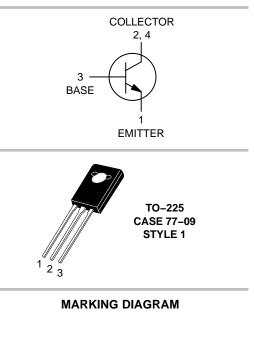
2. Recommend use of thermal compound for lowest thermal resistance. *Indicates JEDEC Registered Data.

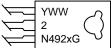


ON Semiconductor®

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1.0 AMPERE GENERAL PURPOSE POWER TRANSISTORS 40–80 VOLTS, 30 WATTS





Y	=	Year
WW	=	Work Week
2N492x	=	Device Code
		x = 1, 2, or 3
G	=	Pb-Free Package

ORDERING INFORMATION

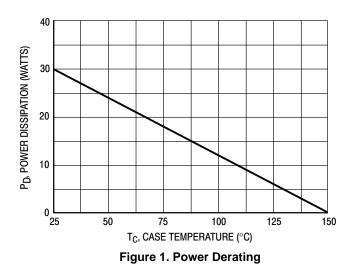
Device	Package	Shipping
2N4921G	TO-225 (Pb-Free)	500 Units / Box
2N4922G	TO-225 (Pb-Free)	500 Units / Box
2N4923G	TO-225 (Pb-Free)	500 Units / Box

** For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 3) ($I_C = 0.1 \text{ Adc}, I_B = 0$) 2N4921G 2N4922G 2N4923G	V _{CEO(sus)}	40 60 80	_ _ _	Vdc
Collector Cutoff Current $(V_{CE} = 20 \text{ Vdc}, I_B = 0)$ 2N4921G $(V_{CE} = 30 \text{ Vdc}, I_B = 0)$	I _{CEO}	_	0.5	mAdc
2N4922G (V _{CE} = 40 Vdc, I _B = 0) 2N4923G		-	0.5 0.5	
$ Collector Cutoff Current \\ (V_{CE} = Rated V_{CEO}, V_{EB(off)} = 1.5 Vdc) \\ (V_{CE} = Rated V_{CEO}, V_{EB(off)} = 1.5 Vdc, T_C = 125^{\circ}C $	ICEX		0.1 0.5	mAdc
Collector Cutoff Current (V_{CB} = Rated V_{CB} , I_E = 0)	I _{CBO}	_	0.1	mAdc
Emitter Cutoff Current ($V_{EB} = 5.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	1.0	mAdc
ON CHARACTERISTICS				
DC Current Gain (Note 3) ($I_C = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 500 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 1.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc}$)	h _{FE}	40 30 10	_ 150 _	-
Collector–Emitter Saturation Voltage (Note 3) $(I_C = 1.0 \text{ Adc}, I_B = 0.1 \text{ Adc})$	V _{CE(sat)}	_	0.6	Vdc
Base–Emitter Saturation Voltage (Note 3) ($I_C = 1.0 \text{ Adc}, I_B = 0.1 \text{ Adc}$)	V _{BE(sat)}	_	1.3	Vdc
Base–Emitter On Voltage (Note 3) ($I_C = 1.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc}$)	V _{BE(on)}	_	1.3	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current–Gain – Bandwidth Product ($I_C = 250 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ MHz}$)	f _T	3.0	-	MHz
Output Capacitance ($V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 100 \text{ kHz}$)	C _{ob}	_	100	pF
Small–Signal Current Gain (I _C = 250 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{fe}	25	-	-

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: PW \approx 300 µs, Duty Cycle \approx 2.0%.



Safe Area Curves are indicated by Figure 5. All limits are applicable and must be observed.

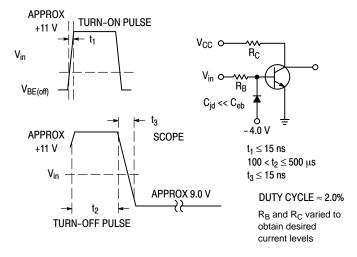


Figure 2. Switching Time Equivalent Circuit

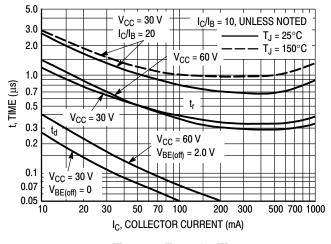


Figure 3. Turn–On Time

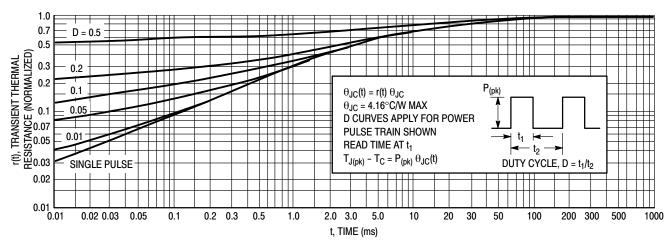


Figure 4. Thermal Response

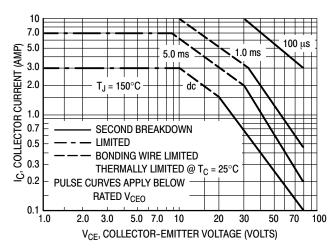
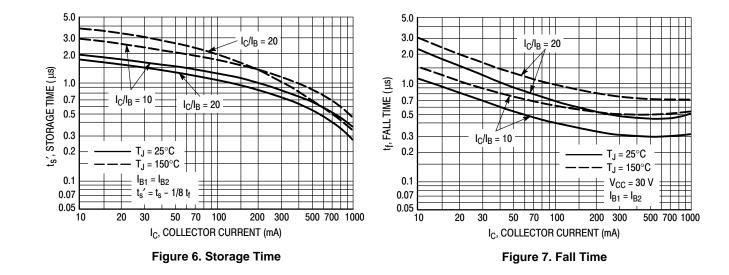
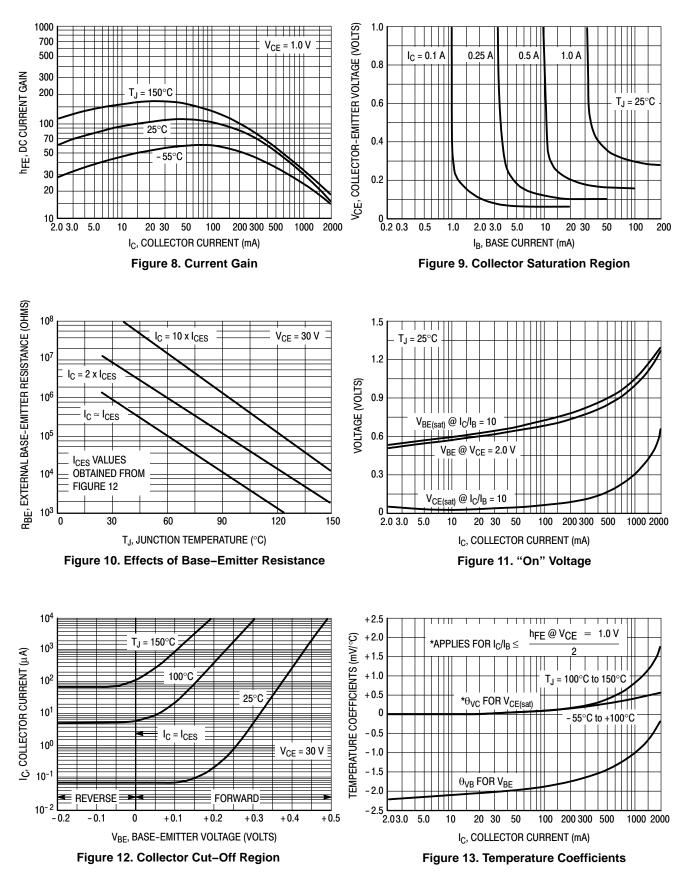


Figure 5. Active-Region Safe Operating Area

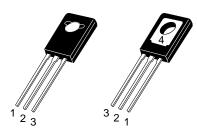
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ operation i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ}C$. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.





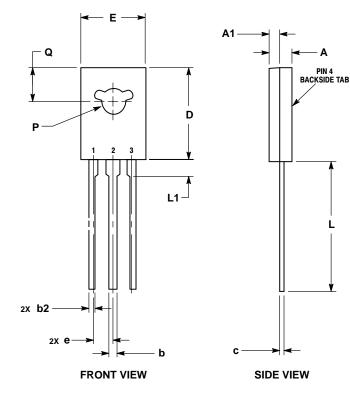
PACKAGE DIMENSIONS



TO-225 CASE 77-09 ISSUE AC

FRONT VIEW

BACK VIEW



NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. NUMBER AND SHAPE OF LUGS OPTIONAL.

	MILLIMETERS			
DIM	MIN	MAX		
Α	2.40	3.00		
A1	1.00	1.50		
b	0.60	0.90		
b2	0.51	0.88		
C	0.39	0.63		
D	10.60	11.10		
E	7.40	7.80		
е	2.04	2.54		
L	14.50	16.63		
L1	1.27	2.54		
Р	2.90	3.30		
Q	3.80	4.20		
STYLE 1: PIN 1. EMITTER 2., 4. COLLECTOR 3. BASE				

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